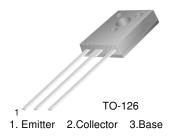


# FJE3303 High Voltage Fast-Switching NPN Power Transistor

- High Voltage Capability
- · High Switching Speed
- · Suitable for Electronic Ballast and Switching Regulator



# Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units V			
V <sub>CBO</sub>	Collector-Base Voltage	700				
V <sub>CEO</sub>	Collector-Emitter Voltage	400 V				
V <sub>EBO</sub>	Emitter-Base Voltage	9	V			
I <sub>C</sub>	Collector Current (DC)	1.5	A			
I <sub>CP</sub>	Collector Current (Pulse) *	3	A			
I <sub>B</sub>	Base Current (DC)	0.75	A			
I <sub>BP</sub>	Base Current (Pulse) *	1.5	A			
P <sub>C</sub>	Collector Dissipation ( $T_C = 25^{\circ}C$ )	20	W			
TJ	Junction Temperature	150	°C			
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C			

\* Pulse Test: Pulse Width = 5ms, Duty Cycle  $\leq 10\%$ 

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units		
BV <sub>CBO</sub>	Collector-Base Breakdwon Voltage	$I_{\rm C} = 500 \mu {\rm A}, \ I_{\rm E} = 0$	700			V		
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0	400			V		
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 500μA, I <sub>C</sub> = 0	$_{\rm E} = 500\mu A, I_{\rm C} = 0$ 9					
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 700V, I <sub>E</sub> = 0			10	μA		
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$	<b>3</b> 5 E					
h <sub>FE1</sub> h <sub>FE2</sub>	DC Current Gain *	$V_{CE} = 2V, I_{C} = 0.5A$ $V_{CE} = 2V, I_{C} = 1.0A$	8 5		21			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$\begin{split} I_{C} &= 0.5A, I_{B} = 0.1A \\ I_{C} &= 1.0A, I_{B} = 0.25A \\ I_{C} &= 1.5A, I_{B} = 0.5A \end{split}$			0.5 1.0 3.0	V V V		
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_{\rm C} = 0.5$ A, $I_{\rm B} = 0.1$ A $I_{\rm C} = 1.0$ A, $I_{\rm B} = 0.25$ A			1.0 1.2	V V		
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.1A$	4			MHz		
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = 10V, f = 0.1MHz		21		pF		
t <sub>ON</sub>	Turn On Time	V <sub>CC</sub> = 125V, I <sub>C</sub> = 1A			1.1	μs		
t <sub>STG</sub>	Storge Time	$I_{B1} = 0.2A, I_{B2} = -0.2A$			4.0	μs		
t <sub>F</sub>	Fall Time	$-R_{L} = 125\Omega$			0.7	μs		

# Electrical Characteristics T<sub>c</sub> = 25°C unless otherwise noted

\* Pulse Test: PW  $\leq$  300 $\mu s,$  Duty Cycle  $\leq$  2%

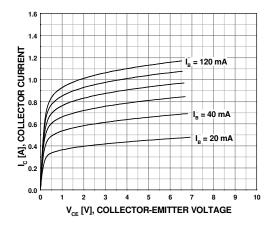
# h<sub>FE</sub> Classification

Classification	H1	H2
h <sub>FE1</sub>	8 ~ 16	14 ~ 21



# **Typical Performance Characteristics**

# Figure 1. Static Characteristic



# Figure 3. Collector-Emitter Saturation Voltage

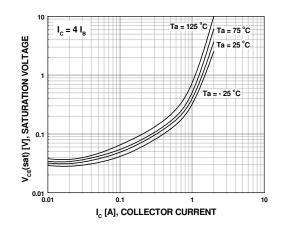
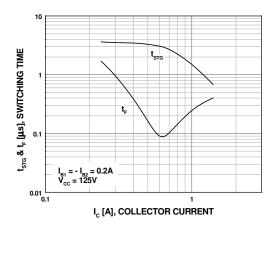
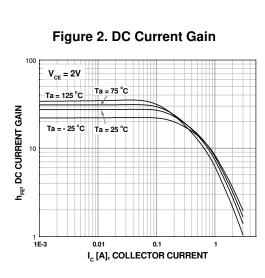


Figure 5. Resistive Load Switching Time







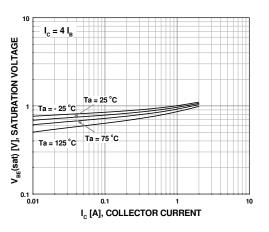
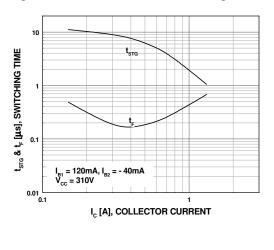
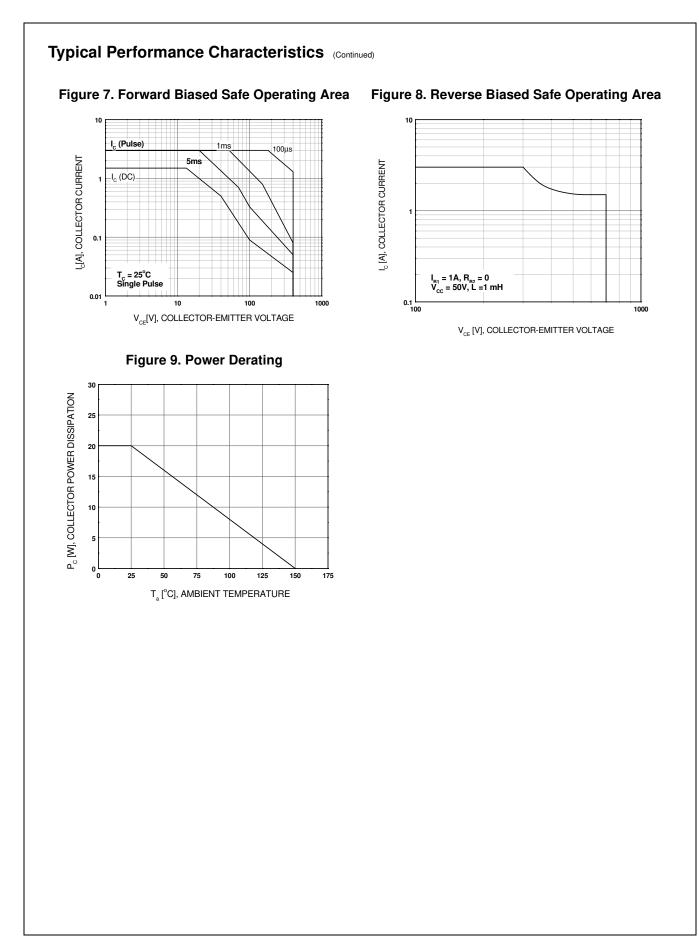
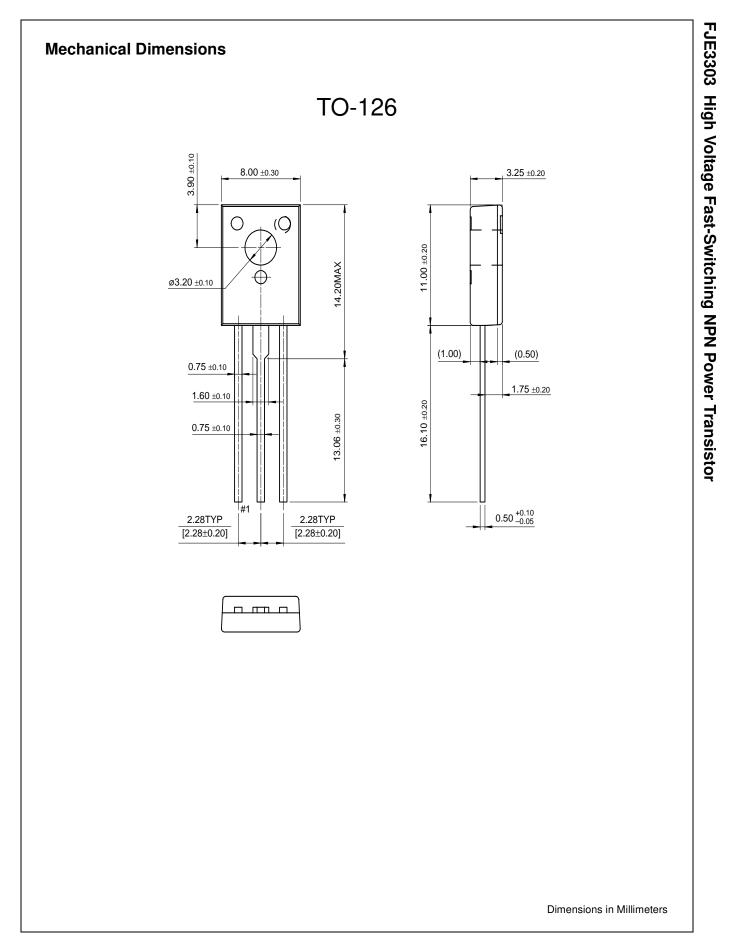


Figure 6. Resistive Load Switching Time







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# FJE3303

NPN Silicon Transistor Planar Silicon Transistor

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•Qualification Support	

### Features

- High Voltage Capability
- High Speed Switching
- Suitable for Electronic Ballast and Switching Regulator

### back to top



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FJE3303H2	Full Production	Full Production	\$0.228	<u>TO-126</u>	3		Line 1: <b>\$Y</b> (Fairchild logo) & <b>3</b> (3-Digit Date Code)
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#### back to top

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